Chip Monolithic Ceramic Capacitors



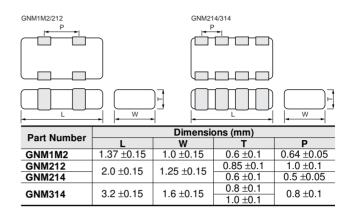
Capacitor Arrays

■ Features

- 1. High density mounting due to mounting space saving
- 2. Mounting cost saving

■ Applications

General electronic equipment



Temperature Compensating Type

Part Number	(GNM31			
LxW	3	3.2x1.6			
тс	C0G (5C)				
Rated Volt.	100 (2A)	50 (1H)			
Capacitance (Capacitance pa	rt numbering code) and T (mm) Dimension (T Dim	nension part numbering code)			
10pF(100)	0.8(4)	0.8(4)			
11pF(110)	0.8(4)	0.8(4)			
12pF(120)	0.8(4)	0.8(4)			
13pF(130)	0.8(4)	0.8(4)			
15pF(150)	0.8(4)	0.8(4)			
16pF(160)	0.8(4)	0.8(4)			
18pF(180)	0.8(4)	0.8(4)			
20pF(200)	0.8(4)	0.8(4)			
22pF(220)	0.8(4)	0.8(4)			
24pF(240)	0.8(4)	0.8(4)			
27pF(270)	0.8(4)	0.8(4)			
30pF(300)	0.8(4)	0.8(4)			
33pF(330)	0.8(4)	0.8(4)			
36pF(360)	0.8(4)	0.8(4)			
39pF(390)	0.8(4)	0.8(4)			
43pF(430)	0.8(4)	0.8(4)			
47pF(470)	0.8(4)	0.8(4)			
51pF(510)	0.8(4)	0.8(4)			
56pF(560)	0.8(4)	0.8(4)			
62pF(620)	0.8(4)	0.8(4)			
68pF(680)	0.8(4)	0.8(4)			
75pF(750)	0.8(4)	0.8(4)			
82pF(820)	0.8(4)	0.8(4)			
91pF(910)	0.8(4)	0.8(4)			
100pF(101)	0.8(4)	0.8(4)			
110pF(111)	0.8(4)	0.8(4)			
120pF(121)	0.8(4)	0.8(4)			
130pF(131)	0.8(4)	0.8(4)			
150pF(151)	0.8(4)	0.8(4)			
160pF(161)		0.8(4)			
180pF(181)		0.8(4)			

Continued from the preceding page.

Part Number	GNM31					
LxW	3.2x1.6					
тс	C0G (5C)					
Rated Volt.	100 (2A) 50 (1H)					
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimen	sion part numbering code)				
200pF(201)		0.8(4)				
220pF(221)		0.8(4)				
240pF(241)		0.8(4)				
270pF(271)		0.8(4)				
300pF(301)	0.8(4)					
330pF(331)		0.8(4)				
360pF(361)		0.8(4)				

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM1 Series

Part Number	GNM1M						
LxW	1.37	1.37x1.00					
тс	X7R (R7)						
Rated Volt.	16 (1C)	10 (1A)					
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimen	sion part numbering code)					
22000pF(223)	0.6(2)						
47000pF(473)	0.6(2)						
0.10∝F(104)		0.6(2)					

The part numbering code is shown in each (). The (2) code in T(mm) means number of elements (two). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM2 Series

Part Number	GNM21
L x W	2.0x1.25
тс	X7R (R7)
Rated Volt.	50 (1H)
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)
1000pF(102)	0.6(4)
10000pF(103)	0.6(4)

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

High Dielectric Constant Type GNM3 Series

Part Number	GNM31						
LxW		3.2x1.6					
тс	X7R (R7)			Y5V (F5)			
Rated Volt.	100 (2A)	50 (1H)	25 (1E)	16 (1C)	100 50 (2A) (1H)		16 (1C)
Capacitance (Capacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)							
220pF(221)	0.8(4)						

Continued from the preceding page.

Part Number				GNM31					
LxW				3.2x1.6					
тс	X7R (R7)					Y5V (F5)			
Rated Volt.	100 (2A)	50 (1H)	25 (1E)	16 (1C)	100 (2A)	50 (1H)	16 (1C)		
Capacitance (Capa	acitance part nur	mbering code) and T	(mm) Dimension	(T Dimension par	t numbering code)				
270pF(271)	0.8(4)								
330pF(331)	0.8(4)								
390pF(391)	0.8(4)	0.8(4)							
470pF(471)	0.8(4)	0.8(4)							
560pF(561)	0.8(4)	0.8(4)							
680pF(681)	0.8(4)	0.8(4)							
820pF(821)	0.8(4)	0.8(4)							
1000pF(102)	0.8(4)	0.8(4)							
1200pF(122)	0.8(4)	0.8(4)							
1500pF(152)	0.8(4)	0.8(4)							
1800pF(182)	0.8(4)	0.8(4)							
2200pF(222)	0.8(4)	0.8(4)			0.8(4)				
2700pF(272)	0.8(4)	0.8(4)							
3300pF(332)	0.8(4)	0.8(4)			0.8(4)				
3900pF(392)	0.8(4)	0.8(4)							
4700pF(472)	0.8(4)	0.8(4)			0.8(4)				
5600pF(562)		0.8(4)							
6800pF(682)		0.8(4)							
8200pF(822)		0.8(4)							
10000pF(103)		0.8(4)							
12000pF(123)		0.8(4)							
15000pF(153)		0.8(4)							
18000pF(183)			0.8(4)						
22000pF(223)				0.8(4)		0.8(4)			
27000pF(273)				0.8(4)					
33000pF(333)				0.8(4)		0.8(4)			
39000pF(393)				0.8(4)					
47000pF(473)				1.0(4)		0.8(4)			
68000pF(683)				1.0(4)		, ,	0.8(4)		
0.10∝F(104)				1.0(4)			0.8(4)		
0.15∝F(154)				, ,			0.8(4)		

The part numbering code is shown in each (). The (4) code in T(mm) means number of elements (four).

Dimensions are shown in mm and Rated Voltage in Vdc.

Specifications and Test Methods

			•	Specifications					
No.	lte	em	Temperature Compensating Type	High Dielectric Type		Test Method			
1	Operating Temperati	ıre Range	5C : −55°C to +125°C	R7 : −55°C to +125°C F5 : −30°C to +85°C					
2	Rated Vo	ltage	See the previous pages.		The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{p,p} or V ^{o,p} , whichever is larger, should be maintained within the rated voltage range.				
3	Appearar	nce	No defects or abnormaliti	es	Visual inspection				
4	Dimensio	n	Within the specified dime	nsions	Using calipers				
5	Dielectric	Strength	No defects or abnormaliti	es	No failure should be observed when 300% of the rated voltage (5C) or 250% of the rated voltage (R7, F5) is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.				
6	Insulation I	Resistance	More than 10,000MΩ or (Whichever is smaller)	500Ω • F	The insulation resista age not exceeding the and within 2 minutes	e rated voltage at 25			
7	Capacita	nce	Within the specified tolera	ance	The capacitance/Q/D quency and voltage s		ired at 25°	C at the fre-	
			30pF max. : Q≥400+20C	Char. 25V min. 16V 10V	Item Char	r. 5C	R7	', F5	
8	(D.F.)	ion ractor	O. Novicel Constitute	R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. F5	Frequency	1±0.1MHz	1±0	.1kHz	
			C : Nominal Capacitance (pF)	F5 0.05 max. 0.07 max. -	Voltage	0.5 to 5Vr.m.s.	1.0±0.	2Vr.m.s.	
		Capacitance Change	Within the specified tolerance (Table A)	Char. Temp. Reference Range Cap. Temp. Temp. Change R7 −55 to +125℃ F5 −30 to +85℃ 25℃ Within±15% Within±25% Within±82%	•	rature stage.	ned using		
		Temperature Coefficient	Within the specified tolerance (Table A)		When cycling the temperature sequentially from step1 through 5, the capacitance should be within the specified tolerance for the temperature coefficient and capacitance				
9	Capacitance				change as Table A The capacitance d differences betwee	•	lividing the	e measured	
9	Temperature Characteristics			Step	Tempera		•		
					1	25±	-2		
		Capacitance		Within ±0.2% or ±0.05 pF		2	-55±3 (for 5C/ R7), -30±3	(for F5)
		Drift	(Whichever is larger)		3	25±			
						5	125±3 (for 5C/F		(F5)
					(2) High Dielectric Co The ranges of cap above 25°C value	nstant Type nacitance change cor over the temperature thin the specified rar	mpared w		
			No removal of the termina	ations or other defect should occur.	Solder the capacitor t	to the test jig (glass	epoxy boa	ard) shown in	
10	Adhesive Strength			b	Fig. 1 using a eutective with the test jig for 10. The soldering should reflow method and shouldering is uniform a	±1 sec. be done either with hould be conducted v	an iron or	using the	
.0	of Termin	ation		<u> </u>	Type GNM1M	a b 0.5 -	c 0.32	d 0.32	
					GNM21	0.5 –	0.32	0.52	
				Solder resist	GNM31	0.8 2.5	0.4	0.8	
				— Copper foil	(in mm) Fig. 1			(in mm)	

Continued on the following page.





Specifications and Test Methods

Continued from the preceding page.

			;	Specifications					
No.	Ite	m	Temperature Compensating Type	High Dielectric Type	Test Method				
		Appearance	No defects or abnormaliti	es	Solder the capacitor to the test jig (glass epoxy board) in the				
		Capacitance	Within the specified tolera	ance	same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion				
11	Vibration Resistance Q/D.F.		30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).				
			No cracking or marking d	efects should occur.	Solder the capacitor on the test jig (glass epoxy board) shown				
10			•GNM□4 •GNM□2 •GNM□1 •GNM□1		in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3 for 5±1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. 20 50 Pressurizing speed: 1.0mm/sec. Pressurize				
12	Deflection	Type GNM1M GNM21 GNM31		b c d 0.05 0.5±0.05 0.32±0.05 0.32±0.05 0.05 0.7±0.05 0.3±0.05 0.2±0.05 0.05 0.8±0.05 0.4±0.05 0.4±0.05 (in mm)	Flexure : ≦1 Capacitance meter 45 45 (in mm) Fig. 3				
				Fig. 2	t=0.8mm (GNM21), 1.6mm (GNM31)				
13	Solderability of Termination 75% of the terminations are to be soldered evenly and continuously.			are to be soldered evenly and	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5°C.				
			The measured and obser specifications in the follow	ved characteristics should satisfy the wing table.					
		Appearance	No marking defects		Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the				
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	capacitor in a eutectic solder solution at 270±5°C for 10±0.5 seconds. Let sit at room temperature for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant				
14	Resistance to Soldering Heat	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max.	type), then measure.				
		G/D.i.	C : Nominal Capacitance (pF)	F5 0.05 max. 0.07 max	• Initial measurement for high dielectric constant type Perform a heat treatment at 150 ± 10 ℃ for one hour and then let sit for 48±4 hours at room temperature. Perform the initial				
		I.R.	More than 10,000M Ω or	500Ω • F (Whichever is smaller)	measurement.				
		Dielectric Strength	No failure						
			The measured and obser specifications in the follow	ved characteristics should satisfy the wing table.	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles				
		Appearance	No marking defects		according to the four heat treatments listed in the following table. Let sit for 24±2 hours (temperature compensating type)				
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	or 48±4 hours (high dielectric constant type) at room temperature, then measure				
15	Temperature Cycle	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. —	Step 1 2 3 4 Temp. (℃) Min. Operating Temp. +3 Temp. Room Temp. +3 Temp. Room Temp. +3 Temp. Room Temp. +3 Temp. Time (min.) 30±3 2 to 3 30±3 2 to 3				
			(pF)		Initial measurement for high dielectric constant type				
		I.R.	More than 10,000M Ω or	500Ω • F (Whichever is smaller)	Perform a heat treatment at 150 ⁺⁰ ₁₀ ℃ for one hour and then				
		Dielectric Strength	No failure		let sit for 48±4 hours at room temperature. Perform the initial measurement.				

Continued on the following page.





Specifications and Test Methods

Continued from the preceding page.

\square	Continued fr	om the prec	eding page.			
			•	Specifications		
No.	Ite	em	Temperature Compensating Type	High Dielectric Type	Test Method	
			The measured and observed characteristics should satisfy the specifications in the following table.			
		Appearance	No marking defects			
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Let the capacitor sit at 40±2°C and 90 to 95% humidity for	
16	Humidity Steady State	Q/D.F.	30pF and over : Q≥350 10pF and over, 30pF and below : Q≥275+5C/2 10pF and below : Q≥200+10C C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure.	
		I.R.	More than 1,000MΩ or 50	$\Omega\Omega$ • F (Whichever is smaller)		
		Dielectric Strength	No failure			
			The measured and observed characteristics should satisfy the specifications in the following table.			
		Appearance	No marking defects			
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Apply the rated voltage at 40±2℃ and 90 to 95% humidity for	
17	Humidity Load	Q/D.F.	30pF and over : Q≥200 30pF and below : Q≥100+10C/3 C : Nominal Capacitance (pF)	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.	
		I.R.	More than 500MΩ or 25Ω	2 • F (Whichever is smaller)		
		Dielectric Strength	No failure			
			The measured and observed characteristics should satisfy the specifications in the following table.			
		Appearance	No marking defects			
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Apply 200% of the rated voltage for 1000±12 hours at the	
18	High Temperature Load	Q/D.F.	30pF and over : Q≥350 10pF and over, 30pF and below :	Char. 25V min. 16V 10V R7 0.025 max. 0.035 max. 0.035 max. F5 0.05 max. 0.07 max. -	maximum operating temperature ±3°C. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA. •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 48±4 hours at room temperature. Perform initial measurement.	
		I.R.	More than 1,000M Ω or 50	DΩ • F (Whichever is smaller)		
		Dielectric Strength	No failure			

Table A

		Capacitance Change from 25℃ (%)					
Char.	Nominal Values (ppm/°C) Note 1	-55		-30		-10	
	(ppiii/ c) Note 1	Max.	Min.	Max.	Min.	Max.	Min.
5C	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11

Note 1 : Nominal values denote the temperature coefficient within a range of 25°C to 125°C.